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Short communication

Synthesis peculiarities of BiVO₃ perovskite

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Abstract

We have experimentally investigated the synthesis of $BiVO_3$ perovskite. We identified the solid-state redox reaction as a process that averts the formation of $BiVO_3$. At elevated temperatures, Bi^{3+} oxidizes V^{3+} to yield metallic Bi and V^{5+} species. This process prevails over the formation of $BiVO_3$. The $BiVO_3$ perovskite structure requires a strong orbital coupling between Bi^{3+} and VO_6 octahedra but this facilitates the electron transfer between V^{3+} and Bi^{3+} . At the investigated temperatures ($>400\,^{\circ}C$), the activation energy for the electron transfer from V to Bi is exceeded and the structure is destabilized, but the synthesis of $BiVO_3$ might be possible at lower temperatures for which the activation energy for the redox reaction is not exceeded.

Keywords: B. X-ray methods; D. perovskites; P. powders: solid state reaction

1. Introduction

Over the last decades, bismuth-based compounds have been extensively studied because of their extraordinary properties that originate from electronic and/or steric influences of the 6s² lone pair of Bi³⁺ and their relatively low toxicity compared to other related compounds that contain heavy metals with a similar electronic structure (e.g., Hg, Cd, Sn, Tl or Pb). In the last years, the interest in the Bi-compounds, especially perovskites, have further escalated because of their potential as lead-free piezoelectrics (BiAlO₃, BiScO₃, BiFeO₃, BiCoO₃, BiGaO₃ and modified versions of these compounds) [1–5], photocatalysts (BiFeO₃, Ga-doped BiFeO₃) [6–8], and multiferroics (BiFeO₃, BiMnO₃, BiCoO₃, BiCrO₃) [9-15]. As a consequence, these compounds have been thoroughly investigated and significant amount of knowledge has been accumulated. Also for other Bi-perovskites, interesting properties have been discovered such as negative thermal expansion and giant magneto-optical Kerr effect in BiNiO₃ [16,17]. In addition to the mentioned compounds, there is a group of simple Bi-perovskites that has not been synthesized yet. There is no information available in the literature about the existence of BiVO₃, BiTiO₃ or BiCuO₃ [18]. It would be wrong to assume that the lack of the literature reports on these compounds indicates that they are not stable. For instance, BiAlO₃ has not been synthesized for a long time but, only after an ab-initio computational study predicted its thermodynamic stability and promising piezoelectric properties, enough experimental efforts have been made to synthesize it [1,19].

The present study focuses on BiVO₃ perovskite, for which promising photocatalytic and/or multiferroic properties are expected by analogy to similar BiFeO3 and BiMnO₃ systems. Bi³⁺ is regarded as a good choice for photocatalytic materials because its 6s² lone electron pair hybridizes with the O 2p orbitals, resulting in an increase in the valence band level [20]. This is why the Bi-based oxide semiconductors exhibit untypically low band gaps (e.g., the band gaps of Bi₂Ti₂O₇ [21], BiFeO₃ [6] or BiVO₄ [22] are 2.8, 2.5, and 2.4 eV, respectively). The Bi 6s-O 2p hybridization is responsible for distortion of the Bi coordination environment, which results in ferroelectricity, while the partially filled d orbitals of V³⁺ are available to induce ferromagnetism. A coupling of the ferroelectricity with the ferromagnetism gives rise to the multiferroic properties, which are of a high fundamental importance

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for material scientists as well as of a high applied value for modern technologies.

Empirical approaches that are used to estimate stability of perovskites predict that BiVO₃ should be stable. The Goldschmidt tolerance factor (t) [23] for BiVO₃ is 0.892 (for ionic radii reported by Shannon [24]), which falls well within the stability limit that is approximately in the range of 0.78–1.05. For the stability of the perovskites, the octahedral factor (r_B/r_O) is as important as the tolerance factor. For BiVO₃ this value was found to be 0.457, which again falls within the stability range that is between 0.414 and 0.732 [25]. Although these numbers predict a stable BiVO₃ perovskite structure, no successful synthesis of BiVO₃ has been reported yet. Only one unsuccessful attempt has been published so far. In the 1970s, Ramadass et al. [26] fired the stoichiometric mixture of Bi₂O₃ and V₂O₃ in a sealed evacuated silica tube. The product was not the BiVO₃ perovskite but described as a cubic defect pyrochlore structure with a Bi₂V₂O_{7-v} composition. Unfortunately, the report on the structural analysis of this pyrochlore is very deficient and does not allow us to judge the correctness of the conclusions.

Because of the high technological interest for this material, we have performed a systematic experimental analysis to find reasons why the BiVO₃ perovskite cannot be synthesized by the solid-state reaction. We have identified chemical processes and interactions that prevent formation of BiVO₃ at elevated temperatures. We present these findings in order to enable synthetic chemists to build on this knowledge and, eventually, perform a successfully synthesis of this compound.

2. Experimental

The stoichiometric mixture of starting reagents, Bi_2O_3 (Alfa Aesar, 99.975%) and V_2O_3 (Alfa Aesar, 97%), was homogenized dry in an agate mortar. The homogenized mixture was pressed into pellets and heat-treated at temperatures ranging from 300 to 900 °C in a sealed tube furnace under N_2 (99.999%). In a separate experiment the mixture was inserted into quartz ampoules and vacuum-sealed at a pressure of $\sim 10^{-6}$ bar. Reference samples consisting of only Bi_2O_3 or V_2O_3 , were heat-treated separately under the same conditions as the stoichiometric mixtures. For the wet chemistry synthesis, a green solution containing $Bi(NO_3)_3 \cdot 5 H_2O$ (Alfa Aesar, 98%) and $V(C_5H_7O_2)_3$ (Alfa Aesar, 97%) in a 1:1 M ratio was first heated at 90 °C and then further processed at temperatures ranging from 400 to 900 °C in a N_2 atmosphere.

The phase characterization was carried out by X-ray powder diffraction using a PANalytical X-ray diffractometer with Cu K_{α} radiation ($\lambda = 0.154$ nm), a step size of 0.017° and collection time of 25.8 s per step. The diffraction patterns were recorded in the range $2\theta = 15-80^{\circ}$. The quantitative analysis of the phases was done using the PANalytical X'Pert HighScore Plus software.

3. Results and discussion

The previous efforts of researchers [18] and our own efforts to synthesize the BiVO3 perovskite by the solid-state reaction from Bi₂O₃ and V₂O₃ have yielded multiphase samples. Our results indicate that the phase composition of nominal BiVO3 after heat treatment depends on the heat treatment conditions and involves phases such as metallic Bi, V₂O₅, BiVO₄, Bi₄V₂O_{10.5}, and Bi_{1.62}V₈O₁₆. The phases with vanadium in different oxidation states are formed, even if a special care has been taken to perform the synthesis in an oxygen-free atmosphere. It is important to note that the same phases were formed when, instead of oxide precursors, we used bismuth(III) and vanadium(III) precursors for the wet-chemical synthesis. This shows that the observed phases are formed as a result of a thermodynamic equilibrium at the applied conditions and their formation is not subjected to a choice of the precursors. It is evident that the synthesis of BiVO₃ cannot be accomplished by the direct reaction of Bi³⁺ and V^{3+} at elevated temperatures due to thermodynamic reasons.

Since no Bi₂O₃-V₂O₃ phase diagrams or any other information regarding their interactions are available in the literature, our further research has been directed into the studies of these interactions in order to identify the processes that avert the formation of BiVO₃. First, two reference samples, Bi₂O₃ and V₂O₃, were separately heattreated in N₂ under atmospheric pressure and in the vacuumed quartz ampoules. The XRD analysis after the thermal treatment showed partial oxidation of V₂O₃ to VO₂ and, in both cases, partial amorphisation (see Fig. 1). The partial oxidation of V₂O₃ could have been caused by the residual oxygen in the atmosphere and/or oxygen species adsorbed on the surface of the V₂O₃ oxide. In the case of Bi₂O₃, no chemical changes were noticed after the heat treatment. Further experiments were performed on the equimolar mixtures of V₂O₃ and Bi₂O₃ that

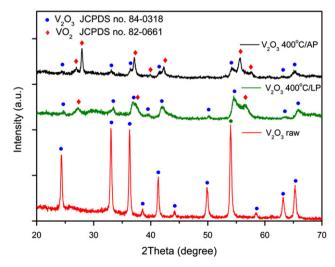


Fig. 1. X-ray diffraction patterns of V_2O_3 before and after thermal treatment at 400 $^{\circ}\text{C}.$

were heat-treated at different temperatures from 300 to 900 °C. The experiments were again performed in N₂ and vacuum; however, no significant influence of the atmosphere was detected. At 300 °C, no interaction between the two oxides was observed. The product contained some VO₂ in accordance with the reference experiment. At 400 °C, the first interaction between both phases was observed. The new phases that formed were metallic Bi and BiVO₄ (see Fig. 2). At the same conditions of the thermal treatment, the reference Bi₂O₃ sample was not reduced to metallic Bi, but in the presence of V₂O₃, metallic Bi appeared as a reaction product. In addition, the reaction yielded BiVO₄ phase with vanadium in +5 valence state. This indicates that the direct reaction of Bi₂O₃ and V₂O₃ does not occur. The reaction is sequential. Initially it is induced by an electron transfer from V³⁺ onto Bi3+, i.e., solid-state redox reaction that yields Bi0 and V^{5+} :

$$2/3 \text{Bi}_2 \text{O}_3 + \text{V}_2 \text{O}_3 \rightarrow 4/3 \text{Bi}^0 + \text{V}_2 \text{O}_5$$
 (1)

At these conditions, V_2O_5 reacts further with unreduced Bi_2O_3 to yield $BiVO_4$ phase:

$$V_2O_5 + Bi_2O_3 \rightarrow 2BiVO_4 \tag{2}$$

 Bi_2O_3 oxidizes V_2O_3 , but also reacts competitively with newly formed V_2O_5 . As a consequence, the redox reaction stops before all V-oxides are consumed. Unfortunately, the much lower electron density and the consequent lower X-ray scattering factors for the V-oxides compared to Bi compounds make the XRD analysis of small concentrations of the V-oxides difficult. In these cases we have not been able to reliably detect and identify the remaining V-oxide phases.

At temperatures above 500 °C, other bismuth vanadates appear (see Fig. 3): predominantly $Bi_{1.62}V_8O_{16}$ and polymorphs of $Bi_4V_2O_{10.5}$ in which vanadium is again in the

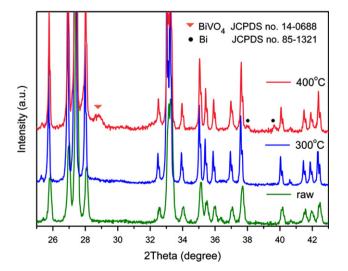


Fig. 2. X-ray diffraction patterns of the equimolar $Bi_2O_3-V_2O_3$ sample before and after the thermal treatment at 300 and 400 °C. The magnification shows a region where the diffraction peaks of the new phases appear.

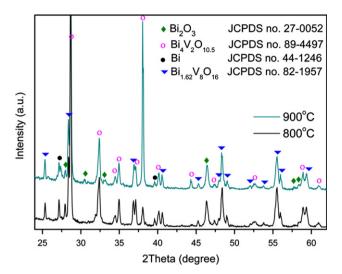


Fig. 3. X-ray diffraction patterns of the equimolar $Bi_2O_3\!\!-\!\!V_2O_3$ sample heated at 800 and 900 $^{\circ}C.$

oxidation state lower than +5. As we have seen, Bi_2O_3 and VO_2/V_2O_3 do not react directly into the binary compounds but rather undergo the described redox process; therefore, the only reaction path that can yield the binary Bi-vanadates with V^{3+} or V^{4+} must go through the reduction of V^{5+} from $BiVO_4$.

$$5.62 \text{BiVO}_4 + 4.38 \text{VO}_x \text{ } T > 600^{\circ}\text{C} \text{ Bi}_4 \text{V}_2 \text{O}_{10.5} + \text{Bi}_{1.62} \text{V}_8 \text{O}_{16}$$
 (3)

The coefficients in Eq. (3) are approximate because the amount of V-oxides was not quantitatively determined.

The experiments show that the reduction-oxidation reaction occurs between Bi^{3+} and V^{3+} already at a very low temperature, around 400 °C. This solid-state redox reaction is a consequence of tendency for covalent bonding between the Bi³⁺, V³⁺ cations and oxygen. To stabilize the BiVO₃ structure and facilitate the short Bi-O bonds (calculated by ab-initio modeling to be $\sim 2.2 \text{ Å}$ —will be reported elsewhere), a strong orbital interaction between Bi³⁺ and VO₆ octahedra is necessary. This reduces the activation energy and facilitates the charge transfer between V^{3+} and Bi^{3+} at fairly low temperatures. The situation is different in the hollandite-type Bi_{1.62}V₈O₁₆ phase (where Bi is in +3 and V in +3 and +4 oxidation states, respectively) wherein the electron transfer between Bi³⁺ and V³⁺ does not take place even at high temperatures (of 800 °C). This indicates higher activation energy for the reduction of Bi³⁺ to the metallic state, probably because in the hollandite-type structure the Bi cations occupy much larger channels (here the Bi-O distance is $\sim 2.5 \text{ Å}$) and interact with the VO₆ octahedra only weakly and with much less covalent contribution to the bonding.

4. Conclusions

Our experimental study of $BiVO_3$ synthesis has identified the reduction–oxidation reaction between Bi^{3+} and V^{3+} as a process that averts the formation of $BiVO_3$.

The formation of BiVO₃ requires a strong orbital coupling between Bi³⁺ and VO₆ octahedra. At such electronic state and at the elevated processing temperatures ($>400\,^{\circ}$ C), the activation energy for the electron transfer from V to Bi is exceeded and the structure is destabilized. The interaction yields metallic Bi and V₂O₅ instead of BiVO₃. However, this result does not necessarily disprove the stability of BiVO₃ or possibility of its formation at lower temperatures. We suggest that a successful synthesis of BiVO₃ might be accomplished by low-temperature synthesis methods (such as hydro(solvo)thermal or even ammonothermal) for which the activation energy for the reduction-oxidation process is not exceeded.

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References

- P. Baettig, C.F. Schelle, R. Le Sar, U.V. Waghmare, N.A. Spaldin, Theoretical prediction of new high-performance lead-Free piezoelectrics, Chemistry of Materials 17 (2005) 1376–1380.
- [2] J. Zylberberg, A.A. Belik, E. Takayama-Muromachiand, Z. Ye, Bismuth aluminate: a new high-t_C lead-free piezo-/ferroelectric, Chemistry of Materials. 19 (2007) 6385–6390.
- [3] T. Zou, X. Wang, H. Wang, C. Zhong, L. Li, I-Wei Chen, Bulk dense fine-grain 1-xBiScO₃-xPbTiO₃ ceramics with high piezo-electric coefficient, Applied Physics Letters 93 (2008) 192913 3.
- [4] K. Oka, M. Azuma, W.T. Chen, A.A. Belik, E. Takayama-Muromachi, M. Mizumaki, N. Ishimatsu, N. Hiraoka, M. Tsujimo, M.G. Tucker, J.P. Attfield, Y. Shimakawa, Pressure-induced spin-state transition in BiCoO₃, Journal of the American Chemical Society. 134 (2010) 9438–9443.
- [5] K. Ujimoto, T. Yoshimura, A. Ashida, N. Fujimura, Direct piezoelectric properties of (1 0 0) and (1 1 1) BiFeO₃ epitaxial thin films, Applied Physics Letters. 100 (2012) 102901 3.
- [6] Y. Zhang, A.M. Schultz, P.A. Salvador, G.S. Rohrer, Y. Zhang, A.M. Schultz, P.A. Salvador, G.S. Rohrer, Spatially selective visible light photocatalytic activity of TiO₂/BiFeO₃ heterostructures, Journal of Materials Chemistry 21 (2011) 4168–4174.
- [7] S. Li, Y.-H. Lin, B.-P. Zhang, Y. Wang, C.-W. Nan, Controlled fabrication of BiFeO₃ uniform microcrystals and their magnetic and photocatalytic behaviors, Journal of Physical Chemistry C 114 (2010) 2903–2908.
- [8] R. Guo, L. Fang, W. Dong, F. Zheng, M. Shen, Enhanced photocatalytic activity and ferromagnetism in Gd doped BiFeO₃ nanoparticles, Journal of Physical Chemistry C 114 (2010) 21390–21396.
- [9] J. Wang, J.B. Neaton, H. Zheng, V. Nagarajan, S.B. Ogale, B. Liu, D. Viehland, V. Vaithyanathan, D.G. Schlom, U.V. Waghmare, N.A. Spaldin, K.M. Rabe, M. Wuttig, R. Ramesh, Epitaxial

- $BiFeO_3$ multiferroic thin film heterostructures, Science 299 (2003) 1719-1722.
- [10] G. Catalan, J.F. Scott, Physics and applications of bismuth ferrite, Advanced Materials 21 (2009) 2463–2485.
- [11] Z.H. Chi, C.J. Xiao, S.M. Feng, F.Y. Li, C.Q. Jin, X.H. Wang, R.Z. Chen, L.T. Li, Manifestation of ferroelectromagnetism in BiMnO₃, Journal of Applied Physics 98 (2005) 103519 5.
- [12] N.A. Hill, K.R. Rabe, First-principles investigation of ferromagnetism and ferroelectricity in bismuth manganite, Physical Review B: Condensed Matter 59 (1999) 8759–8769.
- [13] R. Ramesh, N.A. Spaldin, Multiferroics: progress and prospects in thin films, Nature Materials. 6 (2007) 21–29.
- [14] A.A. Belik, S. Iikubo, K. Kodama, N. Igawa, S. Shamoto, S. Niitaka, M. Azuma, Y. Shimakawa, M. Takano, F. Izumi, E. Takayama-Muromachi, Neutron powder diffraction study on the crystal and magnetic structures of BiCoO₃, Chemistry of Materials. 18 (2006) 798–803.
- [15] N.A. Hill, First principles search for multiferroism in BiCrO₃, Journal of Physical Chemistry B 106 (2002) 3383–3388.
- [16] M. Azuma, W. Chen, H. Seki, M. Czapski, S. Olga, K. Oka, M. Mizumaki, T. Watanuki, N. Ishimatsu, N. Kawamura, S. Ishiwata, M.G. Tucker, Y. Shimakawa, J.P. Attfield, Colossal negative thermal expansion in BiNiO₃ induced by intermetallic charge transfer, Nature Communications 2 (2011) 1–5.
- [17] M.Q. Cai, X. Tan, G.W. Yang, L.Q. Wen, L.L. Wang, W.Y. Hu, Y.G. Wang, Giant Magneto-Optical Kerr, Effects in ferromagnetic perovskite BiNiO₃ with half-metallic state, Journal of Physical Chemistry C 112 (2008) 16638–16642.
- [18] A.A. Belik, Polar and non polar phases of BiMO₃: a review, Journal of Solid State Chemistry 195 (2012) 32–40.
- [19] A.A. Belik, T. Wuernisha, T. Kamiyama, K. Mori, M. Maie, T. Nagai, Y. Matsui, E. Takayama-Muromachi, High-pressure synthesis, crystal structures, and properties of perovskite-like BiAlO₃ and pyroxene-like BiGaO₃, Chemistry of Materials. 18 (2006) 133–139.
- [20] D.J. Payne, M. Robinson, R.G. Egdell, A. Walsh, J. McNulty, K.E. Smith, L.F.J. Piper, Nature of the bismuth lone-pair in BiVO₄, Applied Physics Letters 98 (2011) 212110 3.
- [21] S. Murugesan, M.N. Huda, Y. Yan, M.M. Al-Jassim, V. Subramanian, Band-engineered bismuth titanate pyrochlores for visible light photocatalysis, Journal of Physical Chemistry C 114 (2010) 10598–10605.
- [22] A. Kudo, K. Omori, H. Kato, A. Novel, Aqueous process for preparation of crystal form-controlled and highly crystalline BiVO₄ powder from layered vanadates at room temperature and its photocatalytic and photophysical properties, Journal of the American Chemical Society 121 (1999) 11459–11467.
- [23] V.M. Goldschmidt, Die Gesetze der Krystallochemie (The laws of cristallochemistry), Die Naturwissenschaften 14 (1928) 477–485.
- [24] R.D. Shannon, Revised effective ionic radii and systematic studies of interatomic distances in halides and chaleogenides, Acta Crystallographica Section A: Crystal Physics, Diffraction, Theoretical and General Crystallography 32 (1976) 751–767.
- [25] Z.L. Wang, Z.C. Kang, Perovskites and Related Systems, in Functional and Smart Materials: Structural Evolution and Structure Analysis, Kang Plenum Publishing, New York, 1998 pp. 93–149.
- [26] N. Ramadass, T. Palanisamy, J. Gopalakrishnan, G. Aravamudan, M.V.C. Sastri, Some ABO₃ oxides with defect pyrochlore structure, Solid State Communications 17 (1975) 545–547.